## Supporting Information

## Controlling wrinkle density and height: A new way to increase electrical performance of CVD-grown graphene

Won-Hwa Park,<sup>a,†,</sup> Insu Jo,<sup>b,</sup> Byung Hee Hong <sup>b,\*</sup>, and Hyeonsik Cheong<sup>a,\*</sup>

<sup>a</sup> Department of Physics, Sogang University, Seoul 04107, South Korea. E-mail: <u>hcheong@sogang.ac.kr</u>,

<sup>b</sup> Department of Chemistry, College of Natural Sciences, Seoul National University, Seoul 08826, South Korea. E-mail: <u>byunghee@snu.ac.kr</u>

- + present address: Department of Chemistry, College of Natural Sciences, Seoul National University, Seoul 151-747, South Korea)
- § These authors contributed equally to this work.
- \* Corresponding authors



**Figure S1**. Reproducible data set on ripple formation with corresponding I/V curves for different cooling rate. For each cooling rate, data from different GFETs are presented in different colors.